Silicon Carbide Schottky Diode

650 V, 8 A

FFSB0865B-F085

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

Features

- Max Junction Temperature 175°C
- Avalanche Rated 33 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery / No Forward Recovery
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Automotive HEV-EV Onboard Chargers
- Automotive HEV-EV DC-DC Converters

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Parameter	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage		V_{RRM}	650	V
Single Pulse Avalanche Energy (T _J = 25°C, I _{L(pk)} = 11.5 A, L = 0.5 mH, V = 50 V)		E _{AS}	33	mJ
Continuous Rectified Forward	@ T _C < 147	IF	8.0	Α
Current	@ T _C < 135		10.1	
Non-Repetitive Peak Forward Surge Current	$T_C = 25^{\circ}C$ $t_P = 10 \mu s$	I _{FM}	577	Α
	$T_{C} = 150^{\circ}C$ $t_{P} = 10 \ \mu s$		533	
Non-Repetitive Forward Surge Current (Half-Sine Pulse)	$T_C = 25$ °C $t_P = 8.3$ ms	I _{FSM}	56	Α
Power Dissipation	T _C = 25°C	P _{tot}	73	W
	T _C = 150°C		12	
Operating Junction and Storage T Range	T _J , T _{stg}	-55 to +175	°C	

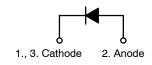
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



ON Semiconductor®

www.onsemi.com

V _{RRM}	I _F
650 V	8.0 A

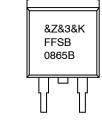


Schottky Diode



D²PAK-2 TO-263 CASE 418BK

MARKING DIAGRAM



&Z &3 = Assembly Plant Code

&3 &K = Numeric Date Code

kK = Lot Code

FFSB0865B = Specific Device Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

FFSB0865B-F085

THERMAL CHARACTERISTICS

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case, Max.	$R_{\theta JC}$	2.05	°C/W

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
ON CHARACTERISTICS						
Forward Voltage	V _F	$I_F = 8.0 \text{ A}, T_J = 25^{\circ}\text{C}$		1.39	1.7	V
		I _F = 8.0 A, T _J = 125°C		1.55	2.0	
		I _F = 8.0 A, T _J = 175°C		1.71	2.4	
Reverse Current	I _R	V _R = 650 V, T _J = 25°C		0.5	40	μΑ
		V _R = 650 V, T _J = 125°C		1.0	80	
		V _R = 650 V, T _J = 175°C		2.0	160	
CHARGES, CAPACITANCES & G	ATE RESISTANCE					
Total Capacitive Charge	Q _C	V _C = 400 V		22		nC
	C _{tot}	V _R = 1 V, f = 100 kHz		336		pF
		V _R = 200 V, f = 100 kHz		39		1

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

 $V_R = 400 \text{ V}, f = 100 \text{ kHz}$

PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Top Marking	Package	Packing Method	Reel Size	Tape Width	Quantity
FFSB0865B-F085	FFSB0865B	D ² PAK	Tape & Reel [†]	330 mm	24 mm	800 Units

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

FFSB0865B-F085

TYPICAL CHARACTERISTICS

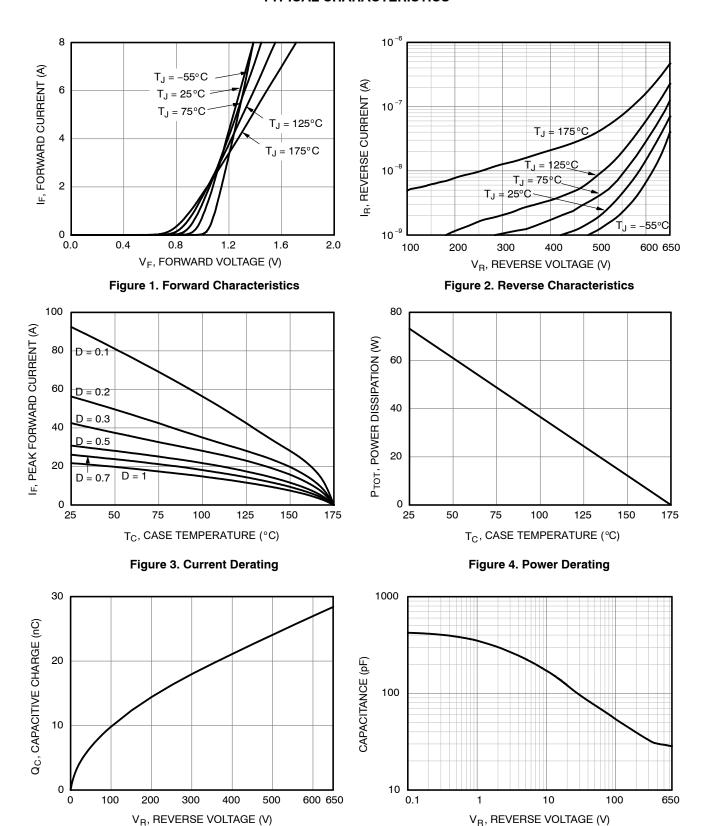


Figure 5. Capacitive Charge vs. Reverse Voltage

Figure 6. Capacitance vs. Reverse Voltage

FFSB0865B-F085

TYPICAL CHARACTERISTICS

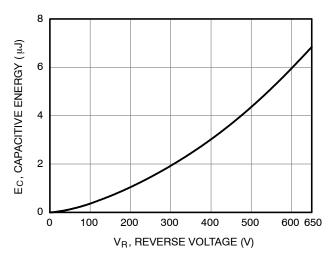


Figure 7. Capacitance Stored Energy

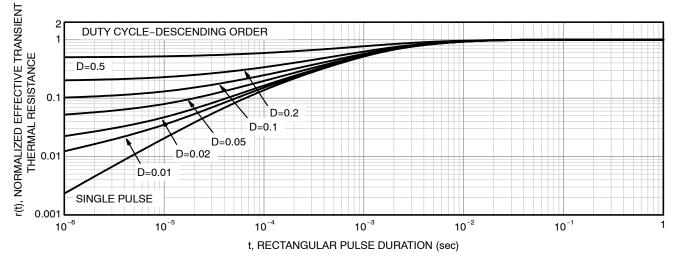
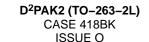
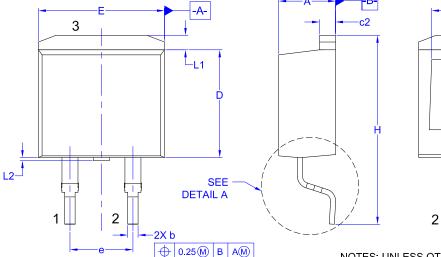
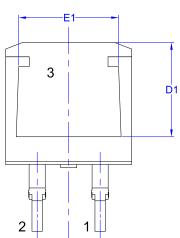


Figure 8. Junction-to-Case Transient Thermal Response



DATE 02 AUG 2018



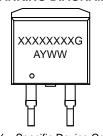


NOTES: UNLESS OTHERWISE SPECIFIED

- A) ALL DIMENSIONS ARE IN MILLIMETERS.
 B) REFERENCE JEDEC, TO-263, VARIATION AB.
- C) DIMENSIONING AND TOLERANCING PER
 DIMENSIONING AND TOLERANCING PER
- ASME Y14.5 2009.
 D) LANDPATTERN RECOMMENDATION PER IPC
- D) LANDPATTERN RECOMMENDATION PER IPO TO254P1524X482-3N

DETAIL A, ROTATED 90°	B)
SCALE: 2X	'(
GAUGE PLANE	D)
M	L3
B 0.10 SEATING —	-A1
GENERIC PLANE	—10.67—— -

GENERIC
MARKING DIAGRAM*



XXX = Specific Device Code

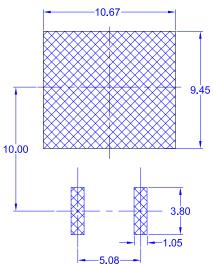
A = Assembly Location

Y = Year

WW = Work Week

G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb–Free indicator, "G" or microdot " ■", may or may not be present. Some products may not follow the Generic Marking.



LAND PATTERN RECOMMENDATION
UNLESS NOTED. ALL DIMS TYPICAL

MIN	NOM	MAX
4.06	4.57	4.83
0.00	0.10	0.25
0.51	0.81	0.99
0.30	0.407	0.74
1.14	1.30	1.65
8.38	8.69	9.65
7.30	7.80	8.30
9.65	10.16	10.67
8.00	8.62	9.00
5.08 BSC		
14.60	15.35	15.88
1.78	2.54	2.79
0.90	1.29	1.68
0.00	0.15	0.25
0.25 BSC		
0° 4° 8°		8°
	4.06 0.00 0.51 0.30 1.14 8.38 7.30 9.65 8.00 14.60 1.78 0.90 0.00	4.06 4.57 0.00 0.10 0.51 0.81 0.30 0.407 1.14 1.30 8.38 8.69 7.30 7.80 9.65 10.16 8.00 8.62 5.08 BS 14.60 15.35 1.78 2.54 0.90 1.29 0.00 0.15 0.25 BS

MILLIMETERS

DOCUMENT NUMBER:	98AON93788G	Electronic versions are uncontrolled except when accessed directly from the Document Repository Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	D ² PAK2 (TO-263-2L)		PAGE 1 OF 1	

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

ON Semiconductor and the are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor and see no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Email Requests to: orderlit@onsemi.com

ON Semiconductor Website: www.onsemi.com

TECHNICAL SUPPORT North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor:

FFSB0865B-F085